## **DP3T Switch for USB/UART/Data Multiplexing**

#### **Brief Description**

The NLAS8252 is a DP3T switch for combined UART and USB 2.0 full speed data applications. It allows portable systems to use a single external port to transmit and receive signals to and from three separate locations within the portable system. It is comprised of two switches, each with a single common I/O that alternates between 3 terminals. They are operated together to allow three data sources, such as a USB or UART transceiver, to pass differential data through a shared USB connector port.

The NLAS8252 features low  $R_{ON}-4~\Omega$  (max) at 4.2 V  $V_{CC}$ , 5  $\Omega$  (typ) at a 3.3 V  $V_{CC}$ . It also features low  $C_{ON}$ , < 30 pF (max) across the supply voltage range. This performance makes it ideal for USB full speed applications that require both low  $R_{ON}$  and  $C_{ON}$  for effective signal transmission.

The NLAS8252 is capable of accepting control input signals down to 1.4 V, over a range of V<sub>CC</sub> supply voltages with minimal leakage current. The NLAS8252 is offered in a lead-free, 12 pin, 1.7 x 2.0 x 0.5 mm, UQFN package.

#### Features

- $R_{ON}$ : 4  $\Omega$  Max @  $V_{CC}$  = 4.2 V
- $C_{ON}$ : < 20 pF @  $V_{CC}$  = 3.3 V
- OVT Protection up to 5.25 V on Common Pins
- V<sub>CC</sub> Range: 1.65 V to 4.5 V
- 3 kV ESD Protection
- 1.7 x 2.0 x 0.5 mm UQFN12 Package
- This is a Pb–Free Device

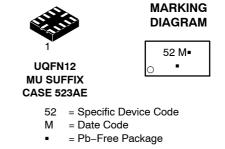
#### **Typical Applications**

- USB/UART/Data Multiplexing
- Shared USB Connector
- Mobile Phones
- Portable Devices



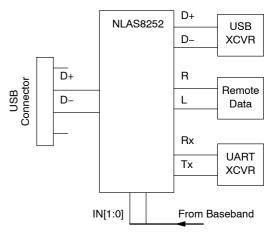
## **ON Semiconductor®**

http://onsemi.com



(Note: Microdot may be in either location)

### APPLICATION DIAGRAM



#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NLAS8252MUTAG	UQFN12 (Pb-Free)	3000 / Tape & Reel

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

## FUNCTIONAL BLOCK DIAGRAM AND PINOUT

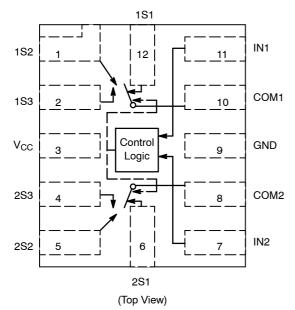


Figure 1. Functional Block Diagram

#### PIN DESCRIPTIONS

Pin#	Name	Direction	Description
1	1S2	I/O	Switch #1 Position 2 Signal Line
2	1S3	I/O	Switch #1 Position 3 Signal Line
3	V <sub>CC</sub>	Input	Power Supply
4	2S3	I/O	Switch #2 Position 3 Signal Line
5	2S2	I/O	Switch #2 Position 2 Signal Line
6	2S1	I/O	Switch #2 Position 1 Signal Line
7	IN2	Input	Bit 1 Control Input Select Line
8	COM2	I/O	Switch #2 Common Signal Line
9	GND	Input	Ground
10	COM1	I/O	Switch #1 Common Signal Line
11	IN1	Input	Bit 0 Control Input Select Line
12	1S1	I/O	Switch #1 Position 1 Signal Line

#### FUNCTION TABLE

IN1 [0]	IN2 [1]	COM1 Closed to:	COM2 Closed to:
0	0	No Connect	No Connect
1	0	1S1	2S1
0	1	1S2	282
1	1	1S3	2S3

## **OPERATING CONDITIONS**

#### MAXIMUM RATINGS

Symbol	Pins	Parameter	Value	Condition	Unit
V <sub>CC</sub>	V <sub>CC</sub>	Positive DC Supply Voltage	-0.5 to +5.5		V
V <sub>IS</sub>	1Sx, 2Sx	Analog Signal Voltage	-0.5 to V <sub>CC</sub> + 0.3		V
	COMx		-0.5 to 5.3		
V <sub>IN</sub>	IN1, IN2	Control Input Voltage	-0.5 to 4.6		V
I <sub>CC</sub>	V <sub>CC</sub>	Positive DC Supply Current	50		mA
I <sub>IS_CON</sub>	1Sx, 2Sx COMx	Analog Signal Continuous Current	±300	Closed Switch	mA
I <sub>IS_PK</sub>	1Sx, 2Sx COMx	Analog Signal Peak Current	±500	10% Duty Cycle	mA
I <sub>IN</sub>	IN1, IN2	Control Input Current	±20		mA
T <sub>STG</sub>		Storage Temperature Range	-65 to 150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Pins	Parameter	Value	Condition	Unit
V <sub>CC</sub>	V <sub>CC</sub>	Positive DC Supply Voltage	1.65 to 4.5		V
V <sub>IS</sub>	1Sx, 2Sx	Analog Signal Voltage	GND to V <sub>CC</sub>		V
	COMx		GND to 4.5		
V <sub>IN</sub>	IN1, IN2	Control Input Voltage	GND to V <sub>CC</sub>		V
T <sub>A</sub>		Operating Temperature Range	-40 to 85		°C

Minimum and maximum values are guaranteed through test or design across the **Recommended Operating Conditions**, where applicable. Typical values are listed for guidance only and are based on the particular conditions listed for each section, where applicable. These conditions are valid for all values found in the characteristics tables unless otherwise specified in the test conditions.

#### ESD PROTECTION

Pins	Description	Minimum Voltage
All Pins	Human Body Model	3 kV

## DC ELECTRICAL CHARACTERISTICS

Symbol	Pins	Parameter	Test Conditions	V <sub>CC</sub>	Min	Тур	Max	Unit
V <sub>IH</sub>	INx	Control Input High	Figures 2	2.7 V 3.3 V 4.2 V	1.25 1.35 1.50			V
V <sub>IL</sub>	INx	Control Input Low	Figures 2	2.7 V 3.3 V 4.2 V			0.4 0.4 0.5	V
I <sub>IN</sub>	INx	Control Input Leakage	V <sub>IS</sub> = GND				±1.0	μA

## CONTROL INPUT (TYPICAL: T = 25°C; $V_{CC}$ = 3.3 V)

## SUPPLY CURRENT AND LEAKAGE (TYPICAL: T = 25°C; V\_{CC} = 3.3 V, V\_{IN} = V<sub>CC</sub> or GND)

Symbol	Pins	Parameter	Test Conditions	V <sub>CC</sub>	Min	Тур	Max	Unit
I <sub>NO/NC</sub> (OFF)	NC, NO	OFF State Leakage	V <sub>COM</sub> = 3.6 V V <sub>NC</sub> = 1.0 V				±1.0	μΑ
I <sub>COM</sub> (ON)	COM	ON State Leakage					±1.0	μA
Icc	V <sub>CC</sub>	Quiescent Supply	$V_{IS} = V_{CC}$ or GND, $I_D = 0$ ;				1.0	μA
IOFF		Power OFF Leakage	V <sub>IS</sub> = GND				1.0	μΑ

## ON RESISTANCE (TYPICAL: T = $25^{\circ}$ C; V<sub>CC</sub> = 3.3 V)

Symbol	Pins	Parameter	Test Conditions	V <sub>cc</sub>	Min	Тур	Max	Unit
R <sub>ON</sub>	1Sx, 2Sx COMx	ON Resistance	$I_{ON}$ = -8 mA, $V_{IS}$ = 0 to $V_{CC}$ ;	2.7 V 3.3 V 4.2 V		5 4 3.5	6 5 4.5	Ω
R <sub>FLAT</sub>	1Sx, 2Sx COMx	R <sub>ON</sub> Flatness	$I_{ON}$ = -8 mA, $V_{IS}$ = 0 to $V_{CC}$ ;	2.7 V 3.3 V 4.2 V			1.3 1.4 1.6	Ω
ΔR <sub>ON</sub>	1Sx, 2Sx COMx	R <sub>ON</sub> Matching	$I_{ON}$ = -8 mA, $V_{IS}$ = 0 to $V_{CC}$ ;	2.7 V 3.3 V 4.2 V		0.35		Ω

### **AC ELECTRICAL CHARACTERISTICS**

Symbol	Pins	Parameter	Test Conditions	Min	Тур	Max	Unit
BW		-3 dB Bandwidth			200		MHz
THD		Total Harmonic Distortion	20 Hz to 20 kHz, 1.0 V <sub>PP</sub>		0.01		%
t <sub>ON</sub>	1Sx to 1Sy, 2Sx to 2Sy	Turn On Time			13	30	nS
t <sub>OFF</sub>	1Sy to 1Sx, 2Sy to 2Sx	Turn Off Time			12	25	nS
t <sub>BBM</sub>	1Sx to 1Sy, 2Sx to 2Sy	Break Before Make		2.0			nS

## TIMING/FREQUENCY (TYPICAL: T = 25°C; V<sub>CC</sub> = 3.3 V, R<sub>L</sub> = 50 $\Omega$ , C<sub>L</sub> = 5 pF, f = 1 MHz)

## CROSSTALK: (TYPICAL: T = 25°C; V<sub>CC</sub> = 3.3V, R<sub>L</sub> = 50 $\Omega$ , C<sub>L</sub> = 35 pF, f = 1MHz)

Symbol	Pins	Parameter	Test Conditions	Min	Тур	Max	Unit
O <sub>IRR</sub>	1Sx or 2Sx	Off Isolation	V <sub>IN</sub> = 0		-60		dB
X <sub>talk</sub>	COMx to COMy	Non-Adjacent Channel			-60		dB

### CAPACITANCE (TYPICAL: T = 25°C; V<sub>CC</sub> = 3.3V, R<sub>L</sub> = 50 $\Omega$ , C<sub>L</sub> = 5 pF, f = 1 MHz)

Symbol	Pins	Parameter	Test Conditions	Min	Тур	Мах	Unit
C <sub>IN</sub>	INx	Control Input	V <sub>CC</sub> = 0 V		3		pF
C <sub>ON</sub>	1Sx or 2Sx to COM	Through Switch	$V_{CC} = 3.3 \text{ V}, V_{IN} = 0 \text{ V}$		16	20	pF
C <sub>OFF</sub>	1Sx, 2Sx COMx	Unselected Port	$V_{CC} = V_{IN} = 3.3 V$		8		pF

#### **Detailed Description**

The NLAS8252 is a DP3T switch designed for applications where a single USB connector is used for multiple data applications within a portable system. Two differential signals from a USB connector can be routed to 3 different end locations. The first, channel 1, is optimized for a full speed, USB 2.0 transceiver. The second and third, channels 2 and 3, are optimized for UART or remote data applications.

#### **Control Inputs Select Logic**

The NLAS8252 is made up of two, 3-throw switches operating off of the same internal enable signal. For each

 $V_{\text{IH}}$  and  $V_{\text{IL}}$  Levels

switch, a signal can pass from the common pin to any of three terminals. Whenever COM1 is closed to terminal 1S2, COM2 will respectively be closed to terminal 2S2. The select logic is controlled by two inputs, IN1 and IN2, connecting the common pins to the terminals according to the function table found on page 2. Since there are four possible control states but only 3 possible terminals, the first combination results in a open connection for all three terminals.

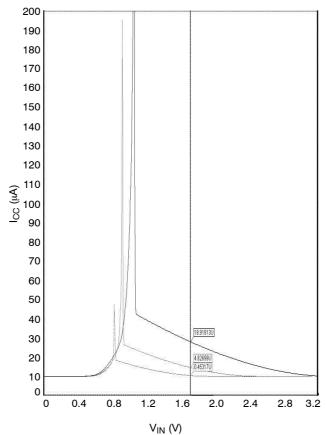
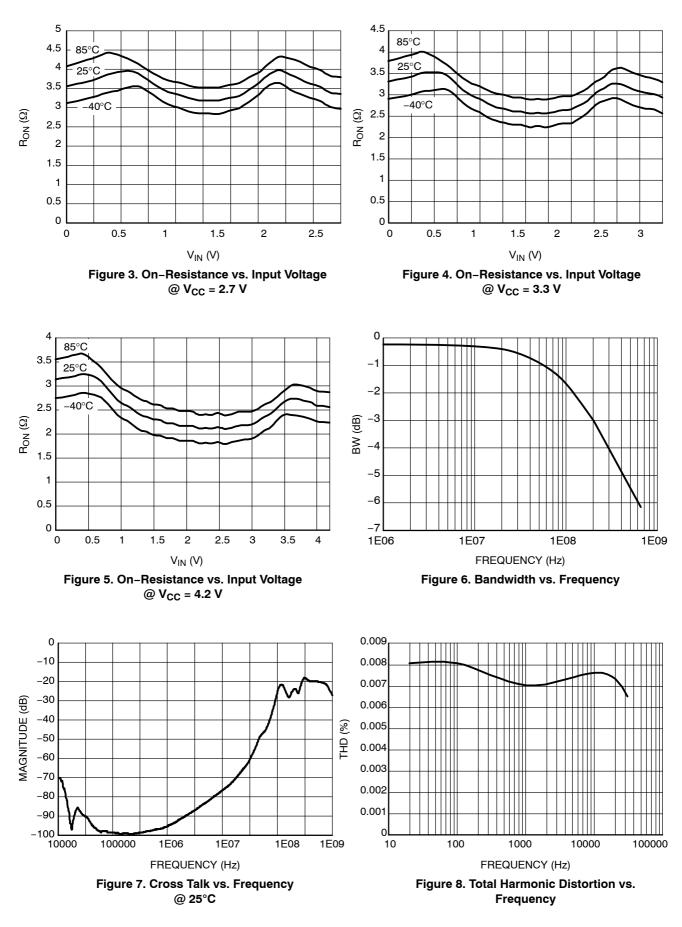
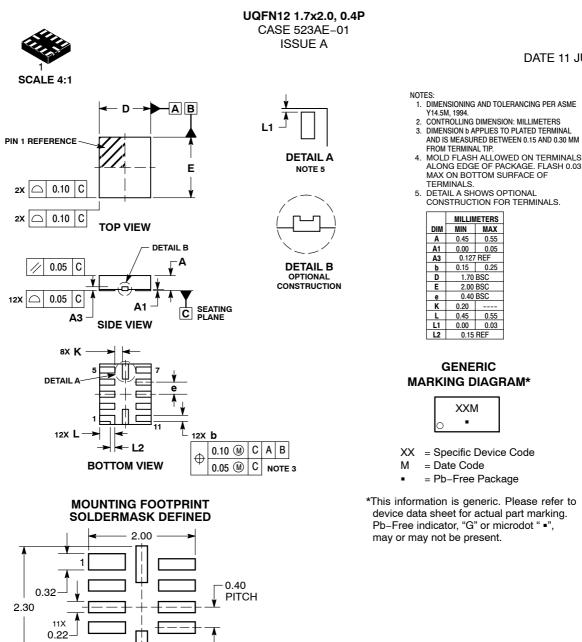


Figure 2. I<sub>CC</sub> Leakage Current vs. V<sub>IN</sub>



#### **MECHANICAL CASE OUTLINE** PACKAGE DIMENSIONS





DIMENSIONS: MILLIMETERS

12X - 0.69

#### DATE 11 JUN 2007

1. DIMENSIONING AND TOLERANCING PER ASME

- ROM TERMINAL TIP. MOLD FLASH ALLOWED ON TERMINALS ALONG EDGE OF PACKAGE. FLASH 0.03 MAX ON BOTTOM SURFACE OF

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
A3	0.127 REF		
b	0.15	0.25	
D	1.70 BSC		
Е	2.00 BSC		
е	0.40 BSC		
Κ	0.20		
L	0.45	0.55	
L1	0.00	0.03	
L2	0.15 REF		

## **MARKING DIAGRAM\***

XX = Specific Device Code

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •",

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